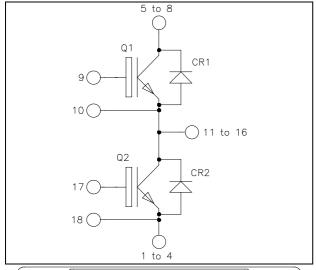
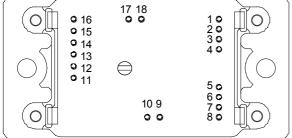


Phase leg Trench + Field Stop IGBT3 Power Module

 $V_{CES} = 600V$ $I_C = 100A$ @ Tc = 80°C





Pins 1/2/3/4 ; 5/6/7/8 ; 11/12/13/14/15/16 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- ullet Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	150	
$I_{\rm C}$		$T_C = 80^{\circ}C$	100	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	340	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	200A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

APTGT100A602G-Rev 1 October, 2012



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				50	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V
	Collector Emitter Saturation Voltage	$I_{\rm C} = 100 A$	$T_j = 150$ °C		1.7		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1.5 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V$, $V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		6100		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		390		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		190		
Q_{G}	Gate charge	V _{GE} =±15V, I _C =100A V _{CE} =300V		1.1		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		115		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		45		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 100A$		225		ns
$T_{\rm f}$	Fall Time	$R_G = 3.3\Omega$		55		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching		130		
$T_{\rm r}$	Rise Time	(150°C)		50		
$T_{d(off)}$	Turn-off Delay Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$		300		ns
T_{f}	Fall Time	$I_C = 100A$ $R_G = 3.3\Omega$		70		
E _{on}	Turn on Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.4		mJ
Lon	Turn on Energy	$V_{\text{Bus}} = 300 \text{V}$ $T_{\text{j}} = 150 ^{\circ} \text{C}$		0.875		1113
E_{off}	Turn off Energy	$I_C = 100A$ $T_j = 25^{\circ}C$		2.5		mJ
Loff	Turn off Energy	$R_G = 3.3\Omega \qquad T_j = 150^{\circ}C$		3.5		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bus} = 360V$ $t_p \le 6\mu s ; T_1 = 150^{\circ}C$		500		A
R_{thJC}	Junction to Case Thermal Resistance				0.44	°C/W

Reverse diode ratings and characteristics

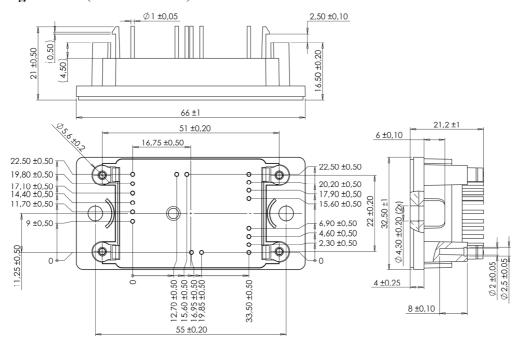
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	$V_R=600V$				50	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		100		Α
$V_{\scriptscriptstyle F}$	Diode Forward Voltage	$I_F = 100A$	$T_i = 25^{\circ}C$		1.6	2	V
V F		$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		
f	Reverse Recovery Time		$T_j = 25$ °C		125		ns
t_{rr}		$I_F = 100A$ $V_R = 300V$ $di/dt = 2000A/\mu s$	$T_{j} = 150^{\circ}C$		220		115
0	Reverse Recovery Charge		$T_j = 25$ °C		4.7		C
Q_{rr}			$T_{\rm j} = 150^{\circ}{\rm C}$		9.9		μС
Б	Reverse Recovery Energy		$T_j = 25$ °C		1.1		ma I
E_{r}			$T_{\rm j} = 150^{\circ}{\rm C}$		2.4		mJ
R_{thJC}	Junction to Case Thermal Resistance					0.77	°C/W



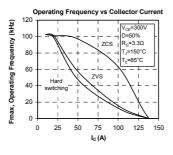
Thermal and package characteristics

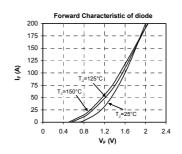
Symbol	Characteristic		Min	Тур	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		175		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

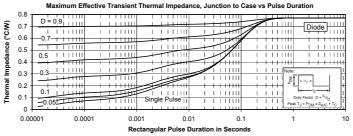
SP2 Package outline (dimensions in mm)



Typical Performance Curve

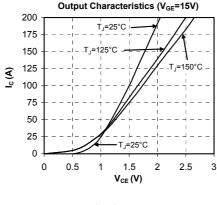


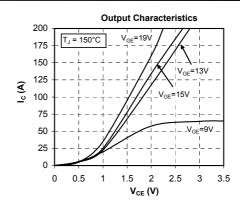


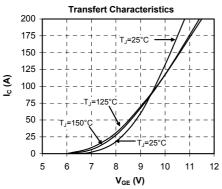


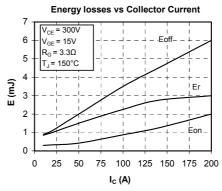
APTGT100A602G-Rev 1 October, 2012

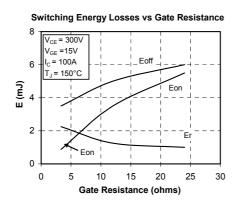


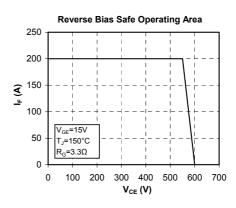


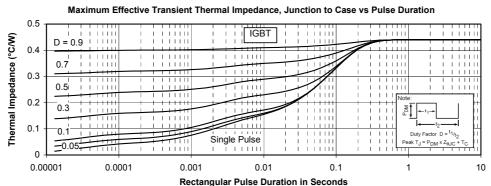














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APTGT100A602G - Rev 1 October, 2012